DS10CP152Q Automotive 1.5 Gbps 2X2 LVDS Crosspoint Switch

Check for Samples: DS10CP152Q

FEATURES

- **AECQ-100 Grade 3**
- **DC - 1.5 Gbps Low Jitter, Low Skew, Low Power Operation**
- **Pin Configurable, Fully Differential, Non-Blocking Architecture**
- **Wide Input Common Mode Voltage Range Allows DC-Coupled Interface to LVDS, CML and LVPECL Drivers**
- **On-Chip 100Ω Input and Output Termination Minimizes Insertion and Return Losses, Reduces Component Count and Minimizes Board Space**
- **8 kV ESD on LVDS I/O Pins Protects Adjoining Components**
- **Small SOIC-16 Space Saving Package**

APPLICATIONS

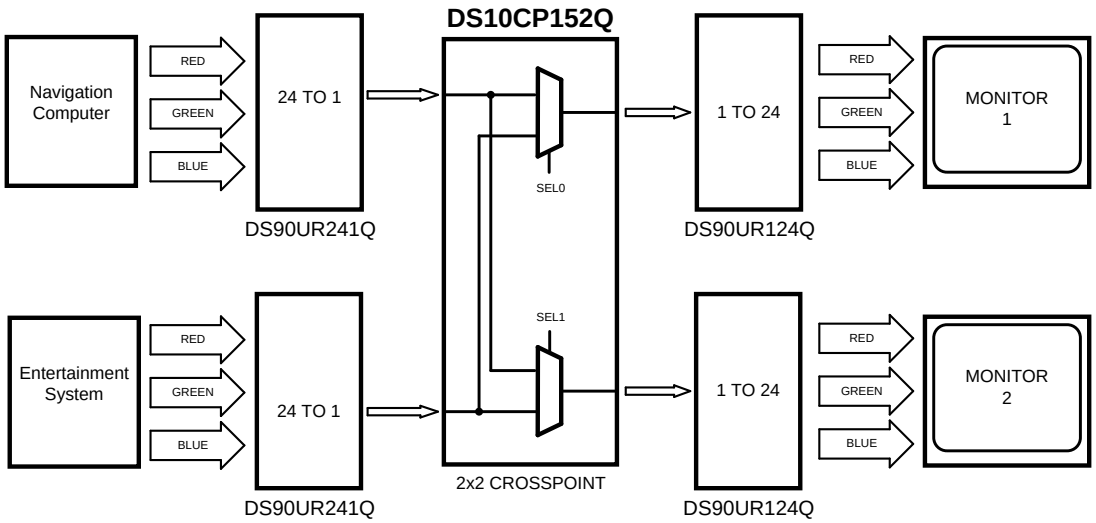
- **Automotive Display Applications**
- **Clock and Data Buffering and Muxing**
- **SD/HD SDI Routers**

DESCRIPTION

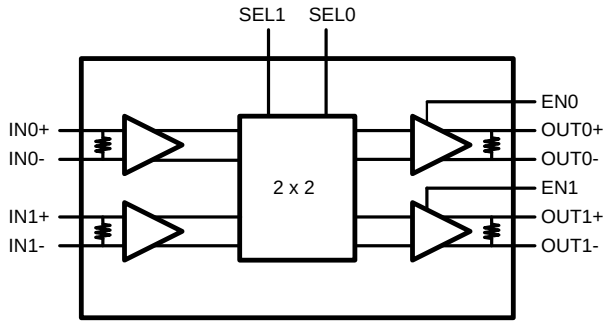
The DS10CP152Q is a 1.5 Gbps 2x2 LVDS crosspoint switch optimized for high-speed signal routing and switching over lossy FR-4 printed circuit board backplanes and balanced cables. Fully differential signal paths ensure exceptional signal integrity and noise immunity. The non-blocking architecture allows connections of any input to any output or outputs.

Wide input common mode range allows the switch to accept signals with LVDS, CML and LVPECL levels; the output levels are LVDS. A very small package footprint requires a minimal space on the board while the flow-through pinout allows easy board layout. Each differential input and output is internally terminated with a 100Ω resistor to lower device return losses, reduce component count and further minimize board space.

Typical Application



Block Diagram



Connection Diagram

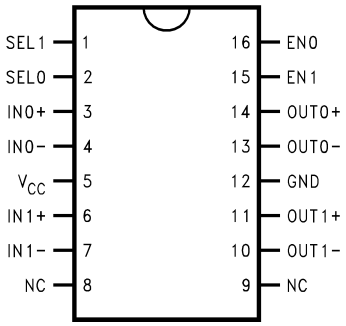


Figure 1. DS10CP152Q Pin Diagram

PIN DESCRIPTIONS

Pin Name	Pin Number	I/O, Type	Pin Description
IN0+, IN0- , IN1+, IN1-	3, 4, 6, 7	I, LVDS	Inverting and non-inverting high speed LVDS input pins.
OUT0+, OUT0-, OUT1+, OUT1-	14, 13, 11, 10	O, LVDS	Inverting and non-inverting high speed LVDS output pins.
SEL1, SEL0	1, 2	I, LVCMOS	Switch configuration pins.
EN0, EN1	16, 15	I, LVCMOS	Output enable pins.
NC	8, 9	NC	"NO CONNECT" pins.
VDD	5	Power	Power supply pin.
GND	12	Power	Ground pin.

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)

Supply Voltage	−0.3V to +4V
LVCMOS Input Voltage	−0.3V to (V_{CC} + 0.3V)
LVDS Input Voltage	−0.3V to +4V
Differential Input Voltage |VID|	1V
LVDS Output Voltage	−0.3V to (V_{CC} + 0.3V)
LVDS Differential Output Voltage	0V to 1V
LVDS Output Short Circuit Current Duration	5 ms
Junction Temperature	+105°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature Range	
Soldering (4 sec.)	+260°C
Maximum Package Power Dissipation at 25°C	
D0016A Package	1.10W
Derate D0016A Package	13.75 mW/°C above +25°C
Package Thermal Resistance	
θ_{JA}	+72.7°C/W
θ_{JC}	+41.2°C/W
ESD Susceptibility	
HBM (3)	≥8 kV
MM (4)	≥250V
CDM (5)	≥1250V

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions.
(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
(3) Human Body Model, applicable std. JESD22-A114C
(4) Machine Model, applicable std. JESD22-A115-A
(5) Field Induced Charge Device Model, applicable std. JESD22-C101-C

Recommended Operating Conditions

	Min	Typ	Max	Units
Supply Voltage (V_{CC})	3.0	3.3	3.6	V
Receiver Differential Input Voltage (V_{ID})	0		1	V
Operating Free Air Temperature (T_A)	−40	+25	+85	°C

DC Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
LVCMOS DC SPECIFICATIONS						
V_{IH}	High Level Input Voltage		2.0		V_{DD}	V
V_{IL}	Low Level Input Voltage		GND		0.8	V

(1) The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.
(2) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V_{OD} and ΔV_{OD}.
(3) Typical values represent most likely parametric norms for V_{CC} = +3.3V and T_A = +25°C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

DC Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
I_{IH}	High Level Input Current	V_{IN} = 3.6V, V_{CC} = 3.6V	40	175	250	µA
I_{IL}	Low Level Input Current	V_{IN} = GND, V_{CC} = 3.6V		±1	±10	µA
V_{CL}	Input Clamp Voltage	I_{CL} = −18 mA, V_{CC} = 0V		−0.9	−1.5	V
LVDS INPUT DC SPECIFICATIONS						
V_{ID}	Input Differential Voltage		0		1	V
V_{TH}	Differential Input High Threshold	V_{CM} = +0.05V or V_{CC}-0.05V		0	+100	mV
V_{TL}	Differential Input Low Threshold		−100	0		mV
V_{CMR}	Common Mode Voltage Range	V_{ID} = 100 mV	0.05		V_{CC} - 0.05	V
I_{IN}	Input Current	V_{IN} = 3.6V or 0V, V_{CC} = 3.6V or 0V		±1	±10	µA
C_{IN}	Input Capacitance	Any LVDS Input Pin to GND		1.7		pF
R_{IN}	Input Termination Resistor	Between IN+ and IN-		100		Ω
LVDS OUTPUT DC SPECIFICATIONS						
V_{OD}	Differential Output Voltage	R_L = 100Ω	250	350	450	mV
ΔV_{OD}	Change in Magnitude of V_{OD} for Complimentary Output States		-35		35	mV
V_{OS}	Offset Voltage	R_L = 100Ω	1.05	1.2	1.375	V
ΔV_{OS}	Change in Magnitude of V_{OS} for Complimentary Output States		-35		35	mV
I_{OS}	Output Short Circuit Current (4)	OUT to GND		-23	-55	mA
		OUT to V_{CC}		8	55	mA
C_{OUT}	Output Capacitance	Any LVDS Output Pin to GND		1.2		pF
R_{OUT}	Output Termination Resistor	Between OUT+ and OUT-		100		Ω
SUPPLY CURRENT						
I_{CC}	Supply Current	EN0 = EN1 = H		58	70	mA
I_{CCZ}	Outputs Powered Down Supply Current	EN0 = EN1 = L		25	30	mA

(4) Output short circuit current (I_{OS}) is specified as magnitude only, minus sign indicates direction only.

AC Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
LVDS OUTPUT AC SPECIFICATIONS						
t_{PLHD}	Differential Propagation Delay Low to High	R_L = 100Ω		440	650	ps
t_{PHLD}	Differential Propagation Delay High to Low			400	650	ps
t_{SKD1}	Pulse Skew $\lvert t_{PLHD} - t_{PHLD} \rvert$ (4)			40	120	ps

(1) The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.
(2) Typical values represent most likely parametric norms for V_{CC} = +3.3V and T_A = +25°C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.
(3) Specification is ensured by characterization and is not tested in production.
(4) t_{SKD1}, $\lvert t_{PLHD} - t_{PHLD} \rvert$, Pulse Skew, is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.

AC Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Conditions		Min	Typ	Max	Units
t_{SKD2}	Channel to Channel Skew (5)				25	60	ps
t_{SKD3}	Part to Part Skew (6)				45	190	ps
t_{LHT}	Rise Time	R_L = 100Ω			170	350	ps
t_{HLT}	Fall Time				170	350	ps
t_{ON}	Output Enable Time				5	20	µs
t_{OFF}	Output Disable Time				3	12	ns
t_{SEL}	Select Time				3	12	ns
JITTER PERFORMANCE (3)							
t_{RJ1}	Random Jitter (RMS Value)	V_{ID} = 350 mV V_{CM} = 1.2V Clock (RZ)	135 MHz		0.5	1.2	ps
t_{RJ2}			311 MHz		0.5	1.2	ps
t_{RJ3}			503 MHz		0.5	1.2	ps
t_{RJ4}			750 MHz		0.5	1.2	ps
t_{DJ1}	Deterministic Jitter (Peak-to-Peak Value)	V_{ID} = 350 mV V_{CM} = 1.2V Clock (RZ)	270 Mbps		9	38	ps
t_{DJ2}			622 Mbps		7	36	ps
t_{DJ3}			1.06 Gbps		7	34	ps
t_{DJ4}			1.5 Gbps		9	35	ps
t_{TJ1}	Total Jitter (Peak to Peak Value)	V_{ID} = 350 mV V_{CM} = 1.2V PRBS-23 (NRZ)	270 Mbps		0.01	0.03	UI_{P-P}
t_{TJ2}			622 Mbps		0.01	0.04	UI_{P-P}
t_{TJ3}			1.06 Gbps		0.01	0.05	UI_{P-P}
t_{TJ4}			1.5 Gbps		0.01	0.07	UI_{P-P}

(5) t_{SKD2}, Channel to Channel Skew, is the difference in propagation delay (t_{PLHD} or t_{PHLD}) among all output channels in Broadcast mode (any one input to all outputs).

(6) t_{SKD3}, Part to Part Skew, is defined as the difference between the minimum and maximum differential propagation delays. This specification applies to devices at the same V_{CC} and within 5°C of each other within the operating temperature range.

DC Test Circuits

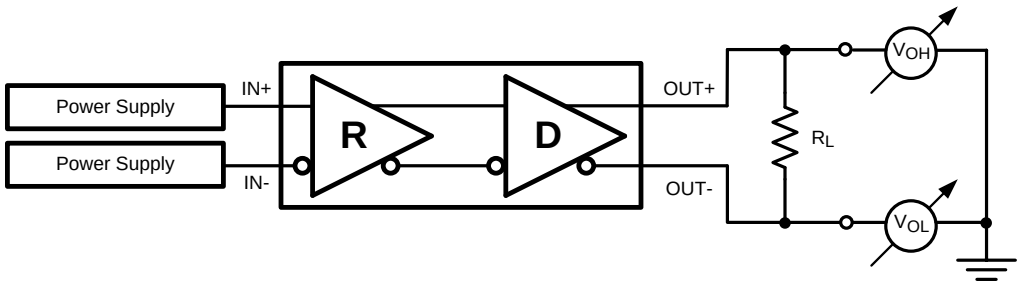


Figure 2.

AC Test Circuits and Timing Diagrams

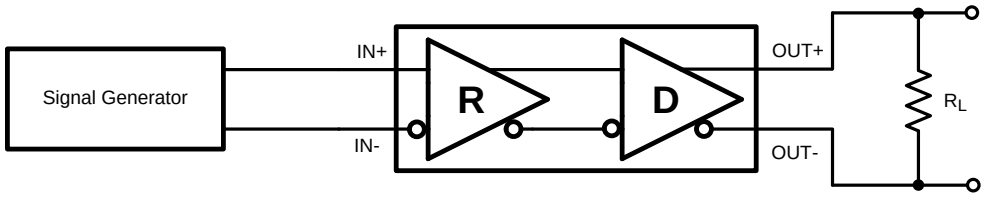


Figure 3.

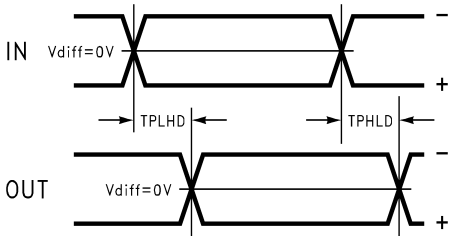


Figure 4.

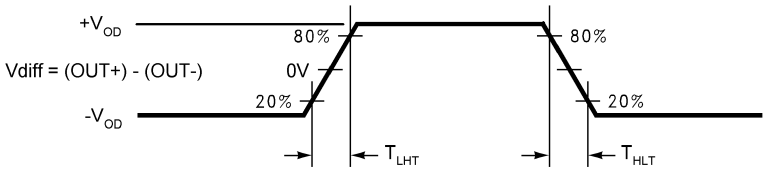


Figure 5.

FUNCTIONAL DESCRIPTION

The DS10CP152Q is a 1.5 Gbps 2x2 LVDS digital crosspoint switch optimized for high-speed signal routing and switching over lossy FR-4 printed circuit board backplanes and balanced cables.

Table 1. Switch Configuration Truth Table

SEL1	SEL0	OUT1	OUT0
0	0	IN0	IN0
0	1	IN0	IN1
1	0	IN1	IN0
1	1	IN1	IN1

Table 2. Output Enable Truth Table

EN1	EN0	OUT1	OUT0
0	0	Disabled	Disabled
0	1	Disabled	Enabled
1	0	Enabled	Disabled
1	1	Enabled	Enabled

INPUT INTERFACING

The DS10CP152Q accepts differential signals and allows simple AC or DC coupling. With a wide common mode range, the DS10CP152Q can be DC-coupled with all common differential drivers (i.e. LVPECL, LVDS, CML). The following three figures illustrate typical DC-coupled interface to common differential drivers. Note that the DS10CP152Q inputs are internally terminated with a 100Ω resistor.

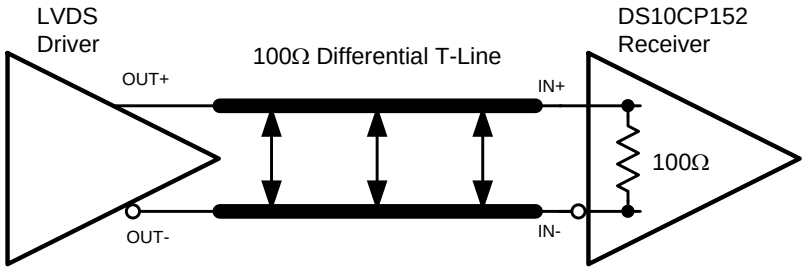


Figure 6. Typical LVDS Driver DC-Coupled Interface to an DS10CP152Q Input

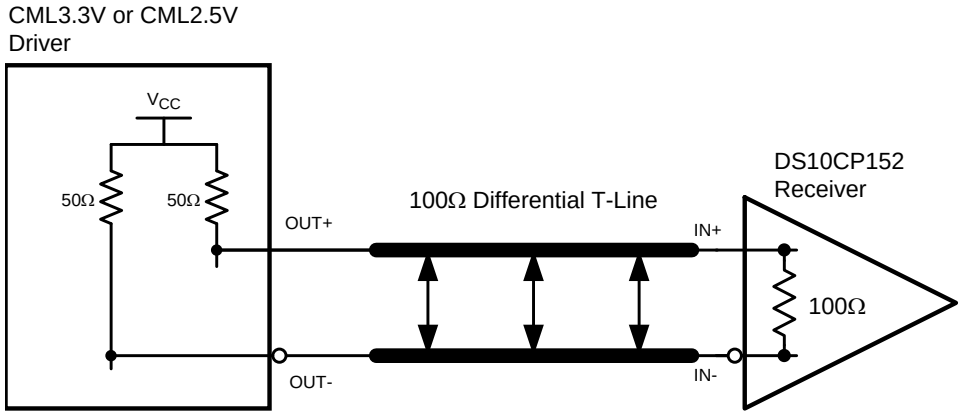


Figure 7. Typical CML Driver DC-Coupled Interface to an DS10CP152Q Input

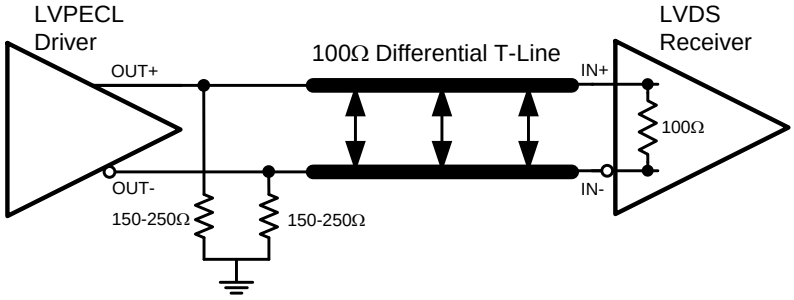


Figure 8. Typical LVPECL Driver DC-Coupled Interface to an DS10CP152Q Input

OUTPUT INTERFACING

The DS10CP152Q outputs signals compliant to the LVDS standard. Its outputs can be DC-coupled to most common differential receivers. The following figure illustrates typical DC-coupled interface to common differential receivers and assumes that the receivers have high impedance inputs. While most differential receivers have a common mode input range that can accomodate LVDS compliant signals, it is recommended to check respective receiver's data sheet prior to implementing the suggested interface implementation.

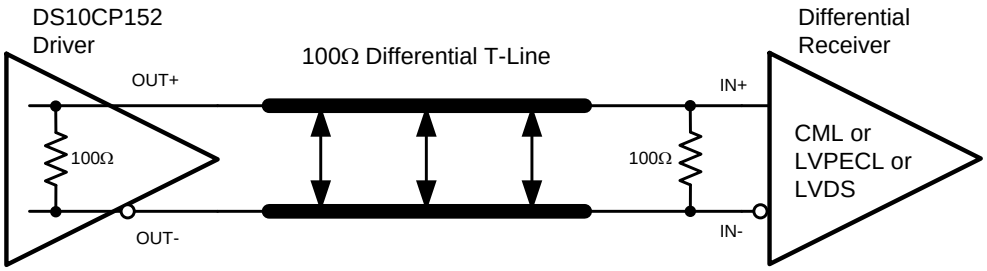


Figure 9. Typical DS10CP152Q Output DC-Coupled Interface to an LVDS, CML or LVPECL Receiver

Typical Performance Characteristics

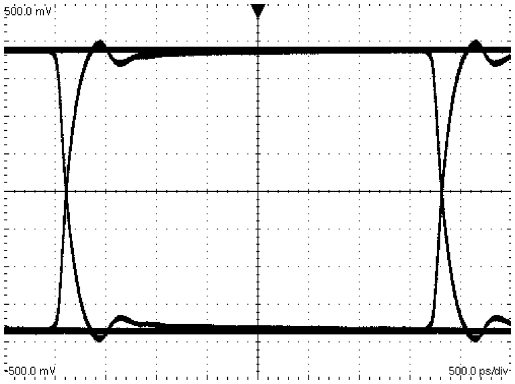


Figure 10. A 270 Mbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:500 ps / DIV

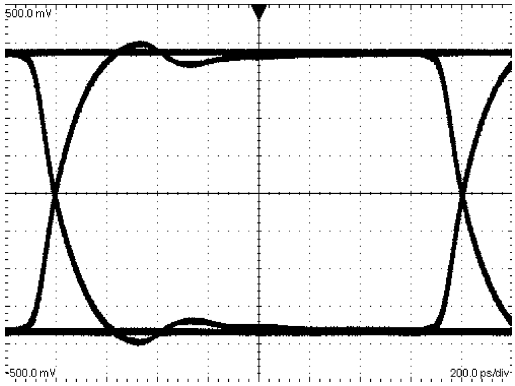


Figure 11. A 622 Mbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:200 ps / DIV

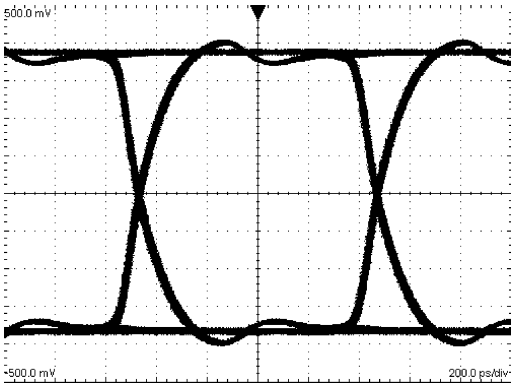


Figure 12. A 1.06 Gbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:200 ps / DIV

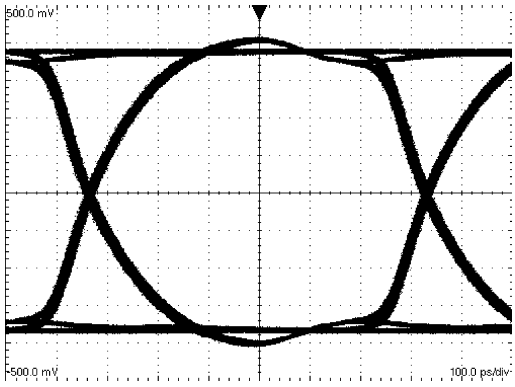


Figure 13. A 1.5 Gbps NRZ PRBS-7 After 2" Differential FR-4 Stripline V:100 mV / DIV, H:100 ps / DIV

REVISION HISTORY

Changes from Revision D (April 2013) to Revision E	Page
• Changed layout of National Data Sheet to TI format	9

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DS10CP152QMA/NOPB	ACTIVE	SOIC	D	16	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	DS10CP152 QMA	Samples
DS10CP152QMAX/NOPB	ACTIVE	SOIC	D	16	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	DS10CP152 QMA	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

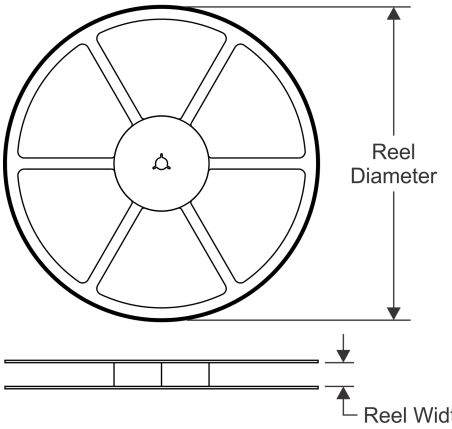
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

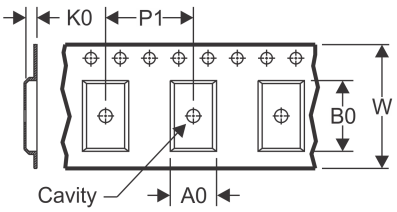
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

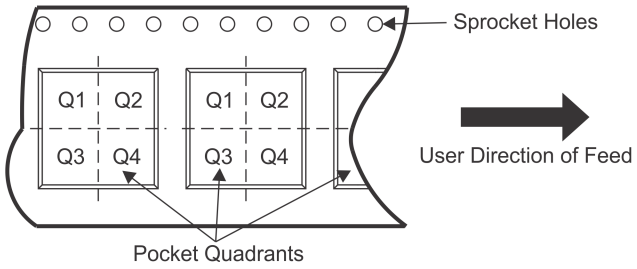


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

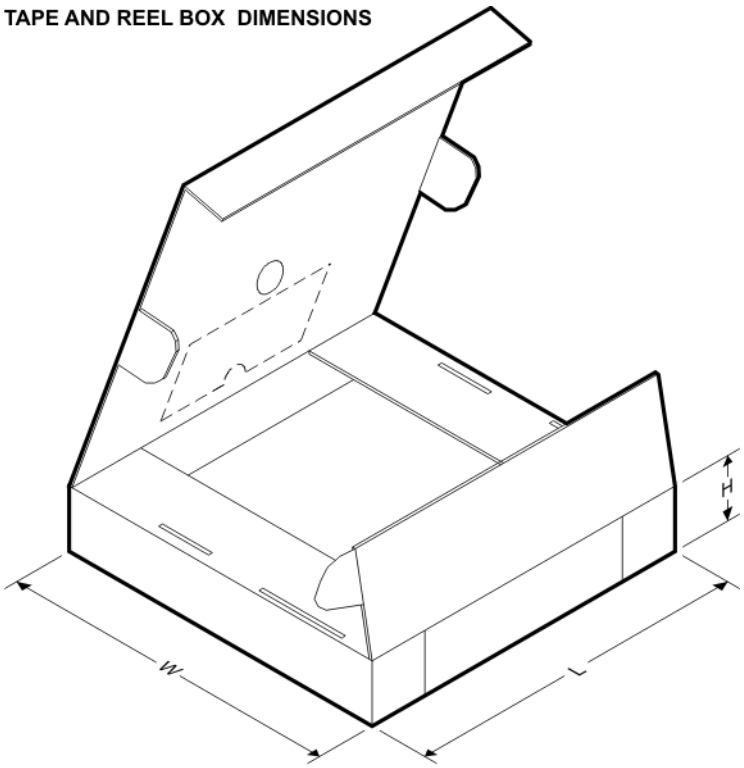
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS10CP152QMA/NOPB	SOIC	D	16	250	178.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1
DS10CP152QMAX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

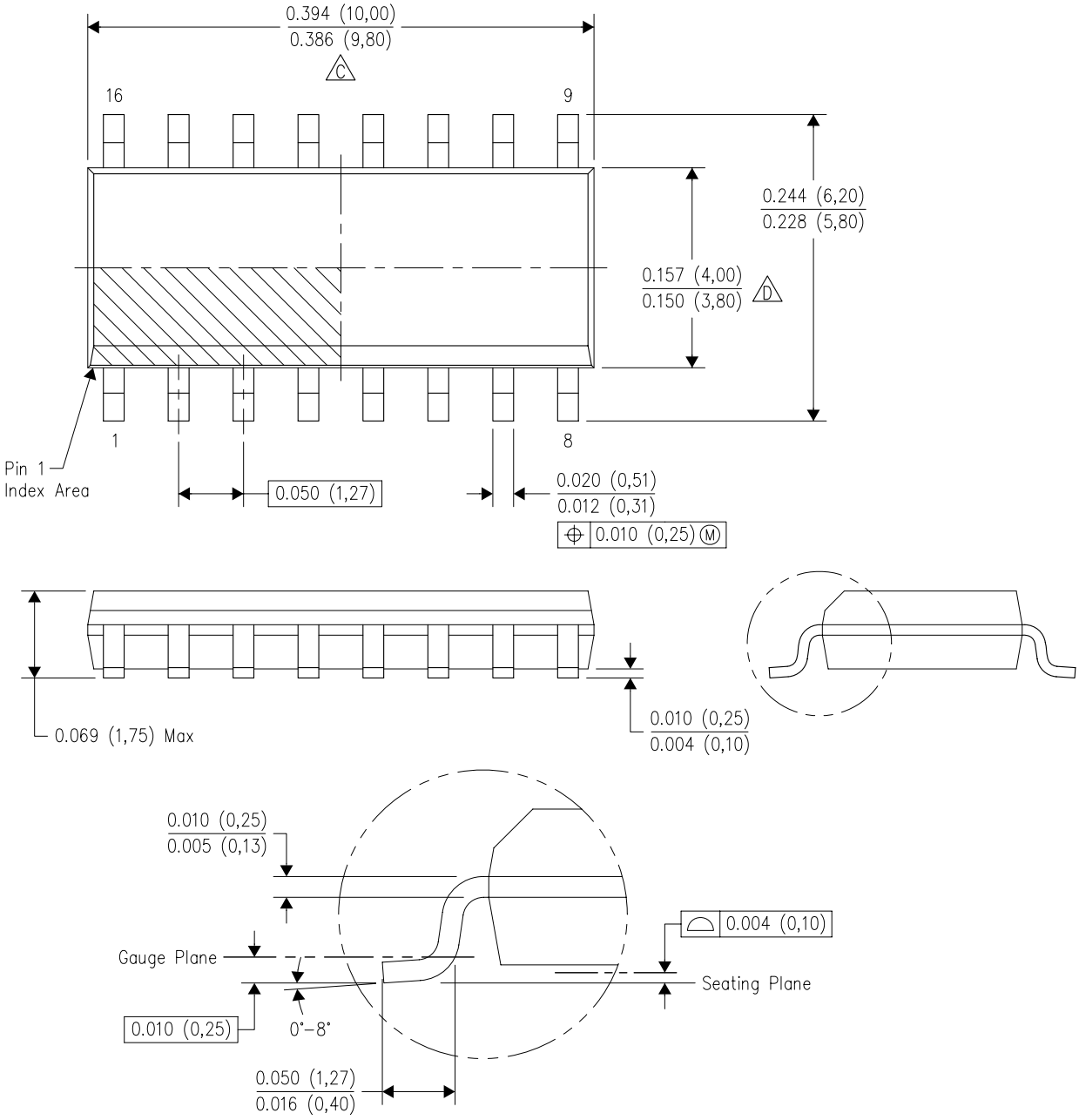
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS10CP152QMA/NOPB	SOIC	D	16	250	210.0	185.0	35.0
DS10CP152QMAX/NOPB	SOIC	D	16	2500	367.0	367.0	35.0

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

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